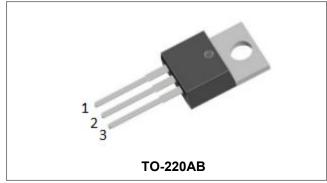


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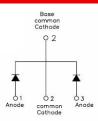
Technical Data Data Sheet N0617, Rev. A



MBR1060CTL SCHOTTKY RECTIFIER



Circuit Diagram



Features

- 125°C TJ operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced
- mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm V _{rwm} Vr	-	60	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=100°C, rectangular wave form	5(Per Leg) 10(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	125	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V _{F1}	@ 5A, Pulse, TJ = 25 °C	0.56	0.60	V
	V _{F2}	@ 5A, Pulse, T _J = 125 °C	0.53	0.55	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = rated V_{R,} T_J = 25 \ ^{\circ}C$	0.09	1.0	mA
	I _{R2}	$@V_R = rated V_R, T_J = 125 \circ C$	20	40	mA
Junction Capacitance(Per Leg)	Ст	@V _R = 5V, T _C = 25 °C f _{SIG} = 1MHz	180	220	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

* Pulse width < 300 µs, duty cycle < 2%</p>

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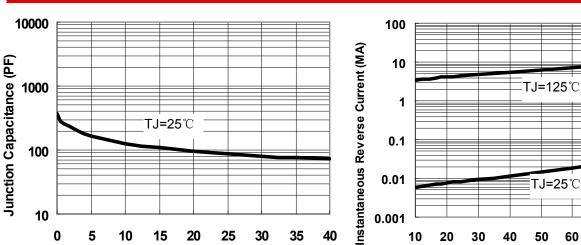
MBR1060CTL

Technical Data Data Sheet N0617, Rev. A

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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +125	°C
Storage Temperature	T _{stg}	-	-55 to +125	°C
Typical Thermal Resistance Junction to Case	R _{θJC}	DC operation	2.0	°C/W
Approximate Weight	wt	-	2	g





Reverse Voltage (V)



50

TJ=25℃

Percent of Rated Peak Reverse Voltage (%)

60

70

80

90

100

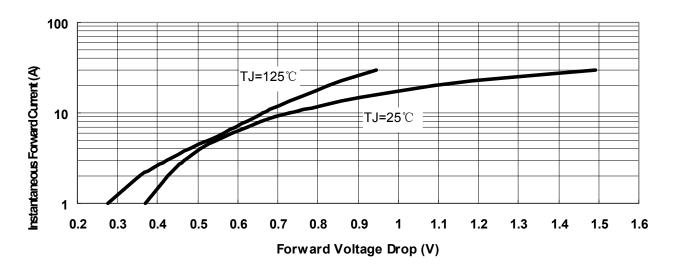


Fig.3-Typical Instantaneous Forward Voltage Characteristics

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Ratings and Characteristics Curves



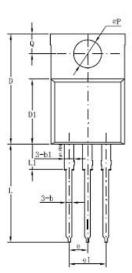
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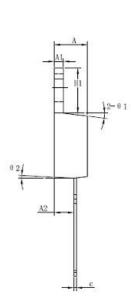
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Mechanical Dimensions TO-220AB

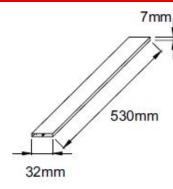






Symbol	Dimensions in millimeters			
-	Min	Typical	Max	
Α	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.52	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
E	10.01	10.16	10.31	
е		2.54		
e1	4.98	5.06	5.18	
H1	6.04	6.24	6.44	
L	12.7	13.56	13.80	
L1	3.56	3.5	3.96	
ΦΡ	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		4 °		

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

- MBR
- = Device Type = Forward Current (10A) = Reverse Voltage(60V) = Configuration = SSG

10 60

CTL SSG

YΥ ww

L

= Year = Week

= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information

Device Package		Shipping	
MBR1060CTL	TO-220AB (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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Technical Data Data Sheet N0617, Rev. A





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